## 74HC137

3-to-8 line decoder, demultiplexer with address latches; inverting

Rev. 4 — 23 December 2015

**Product data sheet** 

## 1. General description

The 74HC137 is a high-speed Si-gate CMOS device and is pin compatible with low power Schottky TTL (LSTTL). The 74HC137 is specified in compliance with JEDEC standard no. 7A.

The 74HC137 is a 3-to-8 line decoder, demultiplexer with latches at the three address inputs (An). The 74HC137 essentially combines the 3-to-8 decoder function with a 3-bit storage latch. When the latch is enabled ( $\overline{\text{LE}}$  = LOW), the 74HC137 acts as a 3-to-8 active LOW decoder. When the latch enable ( $\overline{\text{LE}}$ ) goes from LOW-to-HIGH, the last data present at the inputs before this transition, is stored in the latches. Further address changes are ignored as long as  $\overline{\text{LE}}$  remains HIGH.

The output enable input ( $\overline{E}1$  and E2) controls the state of the outputs independent of the address inputs or latch operation. All outputs are HIGH unless  $\overline{E}1$  is LOW and E2 is HIGH.

The 74HC137 is ideally suited for implementing non-overlapping decoders in 3-state systems and strobed (stored address) applications in bus oriented systems.

## 2. Features and benefits

- Combines 3-to-8 decoder with 3-bit latch
- Multiple input enable for easy expansion or independent controls
- Active LOW mutually exclusive outputs
- Low-power dissipation
- Complies with JEDEC standard no. 7A
- ESD protection:
  - HBM JESD22-A114F exceeds 2000 V
  - MM JESD22-A115-A exceeds 200 V
- Specified from -40 °C to +80 °C and from -40 °C to +125 °C.

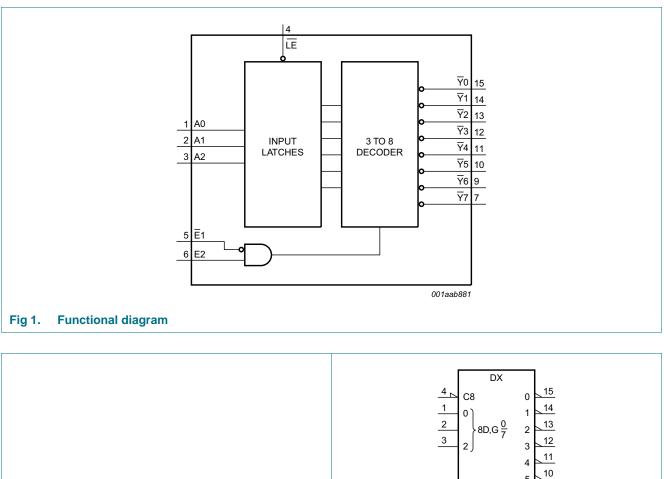
## 3. Ordering information

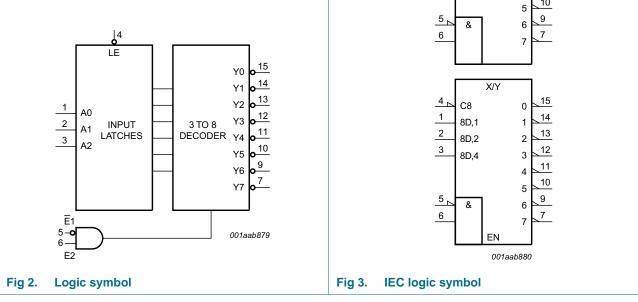
| Table 1. | Ordering | information |
|----------|----------|-------------|
|----------|----------|-------------|

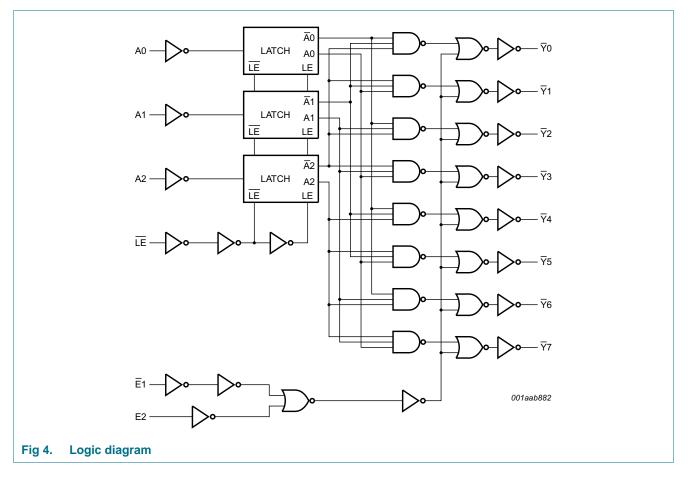
| Type number | Package           |        |  |          |
|-------------|-------------------|--------|--|----------|
|             | Temperature range | Name   | Description  | Version  |
| 74HC137D    | –40 °C to +125 °C | SO16   | plastic small outline package; 16 leads;<br>body width 3.9 mm        | SOT109-1 |
| 74HC137DB   | –40 °C to +125 °C | SSOP16 | plastic shrink small outline package; 16 leads;<br>body width 5.3 mm | SOT338-1 |

# nexperia

## 4. Functional diagram

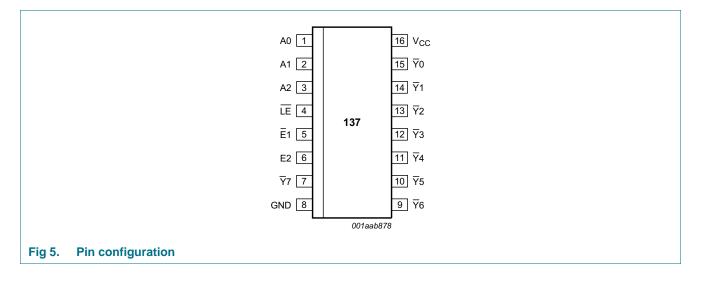






## 5. Pinning information

## 5.1 Pinning



## 5.2 Pin description

| Table 2.Pin description |     |                                   |
|-------------------------|-----|-----------------------------------|
| Symbol                  | Pin | Description                       |
| A0                      | 1   | data input 0                      |
| A1                      | 2   | data input 1                      |
| A2                      | 3   | data input 2                      |
| LE                      | 4   | latch enable input (active LOW)   |
| Ē1                      | 5   | data enable input 1 (active LOW)  |
| E2                      | 6   | data enable input 2 (active HIGH) |
| <u>¥</u> 7              | 7   | multiplexer output 7              |
| GND                     | 8   | ground (0 V)                      |
| <u>¥</u> 6              | 9   | multiplexer output 6              |
| <u>¥</u> 5              | 10  | multiplexer output 5              |
| <u>¥</u> 4              | 11  | multiplexer output 4              |
| <u>¥</u> 3              | 12  | multiplexer output 3              |
| <u>¥</u> 2              | 13  | multiplexer output 2              |
| <u>Y</u> 1              | 14  | multiplexer output 1              |
| <u>Y</u> 0              | 15  | multiplexer output 0              |
| V <sub>CC</sub>         | 16  | positive supply voltage           |

#### **Functional description** 6.

## 6.1 Function table

| Enab | le         |    | Input | :  |    | Output |            |            |            |            |            |            |            |
|------|------------|----|-------|----|----|--------|------------|------------|------------|------------|------------|------------|------------|
| LE   | <b>E</b> 1 | E2 | A0    | A1 | A2 | Y0     | <u>Y</u> 1 | <u>Y</u> 2 | <u>Y</u> 3 | <u>¥</u> 4 | <u>¥</u> 5 | <u>¥</u> 6 | <b>Y</b> 7 |
| Н    | L          | Н  | Х     | Х  | Х  | stable |            |            |            |            |            |            |            |
| Х    | Н          | Х  | Х     | Х  | Х  | Н      | Н          | Н          | Н          | Н          | Н          | Н          | Н          |
| Х    | Х          | L  | Х     | Х  | Х  | Н      | Н          | Н          | Н          | Н          | н          | Н          | Н          |
| L    | L          | Н  | L     | L  | L  | L      | Н          | Н          | Н          | Н          | Н          | Н          | Н          |
|      |            |    | Н     | L  | L  | Н      | L          | Н          | Н          | Н          | Н          | Н          | Н          |
|      |            |    | L     | Н  | L  | Н      | Н          | L          | Н          | Н          | Н          | Н          | Н          |
|      |            |    | Н     | Н  | L  | Н      | Н          | Н          | L          | Н          | Н          | Н          | Н          |
|      |            |    | L     | L  | Н  | Н      | Н          | Н          | Н          | L          | Н          | Н          | Н          |
|      |            |    | Н     | L  | Н  | Н      | Н          | Н          | Н          | Н          | L          | Н          | Н          |
|      |            |    | L     | Н  | Н  | Н      | Н          | Н          | Н          | Н          | Н          | L          | Н          |
|      |            |    | н     | н  | н  | Н      | Н          | Н          | Н          | Н          | Н          | Н          | L          |

[1] H = HIGH voltage level;

L = LOW voltage level;

X = don't care.

## 7. Limiting values

#### Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

| Symbol           | Parameter                     | Conditions  |     | Min  | Max  | Unit |
|------------------|-------------------------------|---|-----|------|------|------|
| V <sub>CC</sub>  | supply voltage                |   |     | -0.5 | +7   | V    |
| I <sub>IK</sub>  | input diode current           | $V_{I} < -0.5 \text{ V or } V_{I} > V_{CC} + 0.5 \text{ V}$ |     | -    | ±20  | mA   |
| I <sub>ОК</sub>  | output diode current          | $V_{\rm O}$ < -0.5 V or $V_{\rm O}$ > $V_{\rm CC}$ + 0.5 V  |     | -    | ±20  | mA   |
| lo               | output source or sink current | $V_{\rm O}$ = –0.5 V to V_{CC} + 0.5 V                      |     | -    | ±25  | mA   |
| I <sub>CC</sub>  | supply current                |   |     | -    | 50   | mA   |
| I <sub>GND</sub> | ground current                |   |     | -50  | -    | mA   |
| T <sub>stg</sub> | storage temperature           |   |     | -65  | +150 | °C   |
| P <sub>tot</sub> | power dissipation             | SO16 and SSOP16 packages                                    | [1] | -    | 500  | mW   |

For SO16 package: P<sub>tot</sub> derates linearly with 8 mW/K above 70 °C.
 For SSOP14 packages: P<sub>tot</sub> derates linearly with 5.5 mW/K above 60 °C.

## 8. Recommended operating conditions

| Table 5. | Recommended | operating | conditions |
|----------|-------------|-----------|------------|
|----------|-------------|-----------|------------|

| Symbol                | Parameter                 | Conditions              | Min | Тур  | Max             | Unit |
|-----------------------|---------------------------|-------------------------|-----|------|-----------------|------|
| V <sub>CC</sub>       | supply voltage            |                         | 2.0 | 5.0  | 6.0             | V    |
| VI                    | input voltage             |                         | 0   | -    | V <sub>CC</sub> | V    |
| Vo                    | output voltage            |                         | 0   | -    | V <sub>CC</sub> | V    |
| $\Delta t / \Delta V$ | input transition rise and | V <sub>CC</sub> = 2.0 V | -   | -    | 625             | ns/V |
|                       | fall rate                 | $V_{CC} = 4.5 V$        | -   | 1.67 | 139             | ns/V |
|                       |                           | $V_{CC} = 6.0 V$        | -   | -    | 83              | ns/V |
| T <sub>amb</sub>      | ambient temperature       |                         | -40 | -    | +125            | °C   |

## 9. Static characteristics

#### Table 6. Static characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

| Symbol                 | Parameter                 | Conditions  | Min  | Тур  | Max  | Unit |
|------------------------|---------------------------|---|------|------|------|------|
| T <sub>amb</sub> = 25  | °C                        |   |      |      |      |      |
| V <sub>IH</sub>        | HIGH-level input voltage  | $V_{CC} = 2.0 V$  | 1.5  | 1.2  | -    | V    |
|                        |                           | $V_{CC} = 4.5 V$  | 3.15 | 2.4  | -    | V    |
|                        |                           | V <sub>CC</sub> = 6.0 V   | 4.2  | 3.2  | -    | V    |
| VIL                    | LOW-level input voltage   | V <sub>CC</sub> = 2.0 V   | -    | 0.8  | 0.5  | V    |
|                        |                           | $V_{CC} = 4.5 V$  | -    | 2.1  | 1.35 | V    |
|                        |                           | V <sub>CC</sub> = 6.0 V   | -    | 2.8  | 1.8  | V    |
| V <sub>OH</sub>        | HIGH-level output voltage | $V_{I} = V_{IH} \text{ or } V_{IL}$   |      |      |      |      |
|                        |                           | $I_{O} = -20 \ \mu A; \ V_{CC} = 2.0 \ V$                                     | 1.9  | 2.0  | -    | V    |
|                        |                           | $I_{O} = -20 \ \mu A; \ V_{CC} = 4.5 \ V$                                     | 4.4  | 4.5  | -    | V    |
|                        |                           | $I_{O} = -20 \ \mu A; \ V_{CC} = 6.0 \ V$                                     | 5.9  | 6.0  | -    | V    |
|                        |                           | $I_{O} = -4 \text{ mA}; V_{CC} = 4.5 \text{ V}$                               | 3.98 | 4.32 | -    | V    |
|                        |                           | $I_{O} = -5.2 \text{ mA}; V_{CC} = 6.0 \text{ V}$                             | 5.48 | 5.81 | -    | V    |
| V <sub>OL</sub>        | LOW-level output voltage  | $V_{I} = V_{IH} \text{ or } V_{IL}$   |      |      |      |      |
|                        |                           | $I_{O} = 20 \ \mu A; \ V_{CC} = 2.0 \ V$                                      | -    | 0    | 0.1  | V    |
|                        |                           | $I_{O} = 20 \ \mu A; \ V_{CC} = 4.5 \ V$                                      | -    | 0    | 0.1  | V    |
|                        |                           | $I_{O} = 20 \ \mu A; \ V_{CC} = 6.0 \ V$                                      | -    | 0    | 0.1  | V    |
|                        |                           | I <sub>O</sub> = 4 mA; V <sub>CC</sub> = 4.5 V                                | -    | 0.15 | 0.26 | V    |
|                        |                           | $I_0 = 5.2 \text{ mA}; V_{CC} = 6.0 \text{ V}$                                | -    | 0.16 | 0.26 | V    |
| I                      | input leakage current     | $V_I = V_{CC}$ or GND; $V_{CC} = 6.0$ V                                       | -    | -    | ±0.1 | μA   |
| СС                     | supply current            | $V_I = V_{CC} \text{ or GND}; I_O = 0 \text{ A};$<br>$V_{CC} = 6.0 \text{ V}$ | -    | -    | 8.0  | μA   |
| Ci                     | input capacitance         |   | -    | 3.5  | -    | pF   |
| Γ <sub>amb</sub> = -40 | 0 °C to +85 °C            |   |      | 1    |      |      |
| / <sub>IH</sub>        | HIGH-level input voltage  | V <sub>CC</sub> = 2.0 V   | 1.5  | -    | -    | V    |
|                        |                           | $V_{CC} = 4.5 V$  | 3.15 | -    | -    | V    |
|                        |                           | V <sub>CC</sub> = 6.0 V   | 4.2  | -    | -    | V    |
| / <sub>IL</sub>        | LOW-level input voltage   | V <sub>CC</sub> = 2.0 V   | -    | -    | 0.5  | V    |
|                        |                           | V <sub>CC</sub> = 4.5 V   | -    | -    | 1.35 | V    |
|                        |                           | V <sub>CC</sub> = 6.0 V   | -    | -    | 1.8  | V    |
| / <sub>ОН</sub>        | HIGH-level output voltage | $V_{I} = V_{IH} \text{ or } V_{IL}$   |      |      |      |      |
|                        |                           | $I_{O} = -20 \ \mu A; \ V_{CC} = 2.0 \ V$                                     | 1.9  | -    | -    | V    |
|                        |                           | $I_{O} = -20 \ \mu A; \ V_{CC} = 4.5 \ V$                                     | 4.4  | -    | -    | V    |
|                        |                           | $I_{O} = -20 \ \mu A; \ V_{CC} = 6.0 \ V$                                     | 5.9  | -    | -    | V    |
|                        |                           | $I_{O} = -4 \text{ mA}; V_{CC} = 4.5 \text{ V}$                               | 3.84 | -    | -    | V    |
|                        |                           | $I_{O} = -5.2 \text{ mA}; V_{CC} = 6.0 \text{ V}$                             | 5.34 | -    | -    | V    |

#### Table 6. Static characteristics ... continued

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

| Symbol                 | Parameter                 | Conditions  | Min  | Тур | Max  | Unit |
|------------------------|---------------------------|---|------|-----|------|------|
| V <sub>OL</sub>        | LOW-level output voltage  | $V_{I} = V_{IH} \text{ or } V_{IL}$                     |      |     |      |      |
|                        |                           | $I_{O} = 20 \ \mu A; \ V_{CC} = 2.0 \ V$                | -    | -   | 0.1  | V    |
|                        |                           | $I_{O} = 20 \ \mu A; \ V_{CC} = 4.5 \ V$                | -    | -   | 0.1  | V    |
|                        |                           | $I_0 = 20 \ \mu A; \ V_{CC} = 6.0 \ V$                  | -    | -   | 0.1  | V    |
|                        |                           | $I_{O} = 4 \text{ mA}; V_{CC} = 4.5 \text{ V}$          | -    | -   | 0.33 | V    |
|                        |                           | $I_{O} = 5.2 \text{ mA}; V_{CC} = 6.0 \text{ V}$        | -    | -   | 0.33 | V    |
| l <sub>i</sub>         | input leakage current     | $V_{I} = V_{CC}$ or GND; $V_{CC} = 6.0$ V               | -    | -   | ±1.0 | μA   |
| I <sub>CC</sub>        | supply current            | $V_I = V_{CC}$ or GND; $I_O = 0$ A;<br>$V_{CC} = 6.0$ V | -    | -   | 80   | μA   |
| T <sub>amb</sub> = -40 | ) °C to +125 °C           |   | I    |     |      | _    |
| V <sub>IH</sub>        | HIGH-level input voltage  | V <sub>CC</sub> = 2.0 V                                 | 1.5  | -   | -    | V    |
|                        |                           | V <sub>CC</sub> = 4.5 V                                 | 3.15 | -   | -    | V    |
|                        |                           | V <sub>CC</sub> = 6.0 V                                 | 4.2  | -   | -    | V    |
| V <sub>IL</sub>        | LOW-level input voltage   | V <sub>CC</sub> = 2.0 V                                 | -    | -   | 0.5  | V    |
|                        |                           | V <sub>CC</sub> = 4.5 V                                 | -    | -   | 1.35 | V    |
|                        |                           | $V_{CC} = 6.0 V$  | -    | -   |      | V    |
| V <sub>OH</sub>        | HIGH-level output voltage | $V_{I} = V_{IH} \text{ or } V_{IL}$                     |      | -   |      |      |
|                        |                           | $I_0 = -20 \ \mu A; \ V_{CC} = 2.0 \ V$                 | 1.9  | -   | -    | V    |
|                        |                           | $I_{O} = -20 \ \mu\text{A}; \ V_{CC} = 4.5 \ \text{V}$  | 4.4  | -   | -    | V    |
|                        |                           | $I_{O} = -20 \ \mu A; \ V_{CC} = 6.0 \ V$               | 5.9  | -   | -    | V    |
|                        |                           | $I_{O} = -4 \text{ mA}; V_{CC} = 4.5 \text{ V}$         | 3.7  | -   | -    | V    |
|                        |                           | $I_{O} = -5.2 \text{ mA}; V_{CC} = 6.0 \text{ V}$       | 5.2  | -   | -    | V    |
| V <sub>OL</sub>        | LOW-level output voltage  | $V_{I} = V_{IH} \text{ or } V_{IL}$                     |      | -   |      |      |
|                        |                           | $I_{O} = 20 \ \mu A; \ V_{CC} = 2.0 \ V$                | -    | -   | 0.1  | V    |
|                        |                           | $I_{O} = 20 \ \mu A; \ V_{CC} = 4.5 \ V$                | -    | -   | 0.1  | V    |
|                        |                           | $I_{O} = 20 \ \mu A; \ V_{CC} = 6.0 \ V$                | -    | -   | 0.1  | V    |
|                        |                           | $I_0 = 4 \text{ mA}; V_{CC} = 4.5 \text{ V}$            | -    | -   | 0.4  | V    |
|                        |                           | $I_0 = 5.2 \text{ mA}; V_{CC} = 6.0 \text{ V}$          | -    | -   | 0.4  | V    |
| I                      | input leakage current     | $V_{I} = V_{CC}$ or GND; $V_{CC} = 6.0$ V               | -    | -   | ±1.0 | μA   |
| lcc                    | supply current            | $V_I = V_{CC}$ or GND; $I_O = 0$ A;<br>$V_{CC} = 6.0$ V | -    | -   | 160  | μA   |

## **10.** Dynamic characteristics

## Table 7. Dynamic characteristics

GND = 0 V;  $t_r = t_f = 6$  ns;  $C_L = 50$  pF.

| Symbol                | Parameter                     | Conditions  | Min | Тур | Max | Unit |
|-----------------------|-------------------------------|---|-----|-----|-----|------|
| Г <sub>атb</sub> = 25 | <b>O</b> °                    |   |     |     |     |      |
| pd                    | propagation delay             | An to Yn; see Figure 6 [1]                              |     |     |     |      |
|                       |                               | V <sub>CC</sub> = 2.0 V                                 | -   | 58  | 180 | ns   |
|                       |                               | V <sub>CC</sub> = 4.5 V                                 | -   | 21  | 36  | ns   |
|                       |                               | V <sub>CC</sub> = 6.0 V                                 | -   | 17  | 31  | ns   |
|                       |                               | $V_{CC} = 5.0 \text{ V}; \text{ C}_{L} = 15 \text{ pF}$ | -   | 18  | -   | ns   |
|                       |                               | LE to Yn; see Figure 7                                  |     |     |     |      |
|                       |                               | V <sub>CC</sub> = 2.0 V                                 | -   | 55  | 190 | ns   |
|                       |                               | V <sub>CC</sub> = 4.5 V                                 | -   | 20  | 38  | ns   |
|                       |                               | $V_{CC} = 6.0 V$  | -   | 16  | 32  | ns   |
|                       |                               | V <sub>CC</sub> = 5.0 V; C <sub>L</sub> = 15 pF         | -   | 17  | -   | ns   |
|                       |                               | E1 to Yn; see Figure 7                                  |     |     |     |      |
|                       |                               | V <sub>CC</sub> = 2.0 V                                 | -   | 50  | 145 | ns   |
|                       |                               | V <sub>CC</sub> = 4.5 V                                 | -   | 18  | 29  | ns   |
|                       |                               | $V_{CC} = 6.0 V$  | -   | 14  | 25  | ns   |
|                       |                               | V <sub>CC</sub> = 5.0 V; C <sub>L</sub> = 15 pF         | -   | 15  | -   | ns   |
|                       |                               | E2 to $\overline{Y}$ n; see Figure 6                    |     |     |     |      |
|                       |                               | V <sub>CC</sub> = 2.0 V                                 | -   | 50  | 145 | ns   |
|                       |                               | V <sub>CC</sub> = 4.5 V                                 | -   | 18  | 29  | ns   |
|                       |                               | V <sub>CC</sub> = 6.0 V                                 | -   | 14  | 25  | ns   |
|                       |                               | V <sub>CC</sub> = 5.0 V; C <sub>L</sub> = 15 pF         | -   | 15  | -   | ns   |
| t                     | transition time               | see Figure 6 [2]  |     |     |     |      |
|                       |                               | V <sub>CC</sub> = 2.0 V                                 | -   | 19  | 75  | ns   |
|                       |                               | V <sub>CC</sub> = 4.5 V                                 | -   | 7   | 15  | ns   |
|                       |                               | V <sub>CC</sub> = 6.0 V                                 | -   | 6   | 13  | ns   |
| W                     | pulse width                   | LE HIGH; see Figure 8                                   |     |     |     |      |
|                       |                               | V <sub>CC</sub> = 2.0 V                                 | 50  | 11  | -   | ns   |
|                       |                               | V <sub>CC</sub> = 4.5 V                                 | 10  | 4   | -   | ns   |
|                       |                               | V <sub>CC</sub> = 6.0 V                                 | 9   | 3   | -   | ns   |
| su                    | set-up time                   | An to LE; see Figure 8                                  |     |     |     |      |
|                       |                               | V <sub>CC</sub> = 2.0 V                                 | 50  | 3   | -   | ns   |
|                       |                               | V <sub>CC</sub> = 4.5 V                                 | 10  | 1   | -   | ns   |
|                       |                               | V <sub>CC</sub> = 6.0 V                                 | 9   | 1   | -   | ns   |
| h                     | hold time                     | An to LE; see Figure 8                                  |     |     |     |      |
|                       |                               | V <sub>CC</sub> = 2.0 V                                 | 30  | 3   | -   | ns   |
|                       |                               | V <sub>CC</sub> = 4.5 V                                 | 6   | 1   | -   | ns   |
|                       |                               | $V_{\rm CC} = 6.0 \text{ V}$                            | 5   | 1   | -   | ns   |
| C <sub>PD</sub>       | power dissipation capacitance | $V_{I} = GND \text{ to } V_{CC}$ [3]                    | -   | 57  | -   | pF   |

| Symbol                | Parameter         | Conditions  | Min | Тур | Max | Unit |
|-----------------------|-------------------|---|-----|-----|-----|------|
| T <sub>amb</sub> = -4 | 0 °C to +85 °C    |   | 1   |     | 1   |      |
| t <sub>pd</sub>       | propagation delay | An to Yn; see Figure 6                            |     |     |     |      |
|                       |                   | $V_{CC} = 2.0 V$                                  | -   | -   | 225 | ns   |
|                       |                   | $V_{CC} = 4.5 V$                                  | -   | -   | 45  | ns   |
|                       |                   | V <sub>CC</sub> = 6.0 V                           | -   | -   | 38  | ns   |
|                       |                   | LE to Yn; see Figure 7                            |     |     |     |      |
|                       |                   | V <sub>CC</sub> = 2.0 V                           | -   | -   | 240 | ns   |
|                       |                   | $V_{CC} = 4.5 V$                                  | -   | -   | 48  | ns   |
|                       |                   | V <sub>CC</sub> = 6.0 V                           | -   | -   | 41  | ns   |
|                       |                   | $\overline{E}1$ to $\overline{Y}n$ ; see Figure 7 |     |     |     |      |
|                       |                   | $V_{CC} = 2.0 V$                                  | -   | -   | 180 | ns   |
|                       |                   | $V_{CC} = 4.5 V$                                  | -   | -   | 36  | ns   |
|                       |                   | $V_{CC} = 6.0 V$                                  | -   | -   | 31  | ns   |
|                       |                   | E2 to $\overline{Y}$ n; see Figure 6              |     |     |     |      |
|                       |                   | V <sub>CC</sub> = 2.0 V                           | -   | -   | 180 | ns   |
|                       |                   | $V_{CC} = 4.5 V$                                  | -   | -   | 36  | ns   |
|                       |                   | V <sub>CC</sub> = 6.0 V                           | -   | -   | 31  | ns   |
| t <sub>t</sub>        | transition time   | see Figure 6                                      |     |     |     |      |
|                       |                   | V <sub>CC</sub> = 2.0 V                           | -   | -   | 95  | ns   |
|                       |                   | $V_{CC} = 4.5 V$                                  | -   | -   | 19  | ns   |
|                       |                   | V <sub>CC</sub> = 6.0 V                           | -   | -   | 16  | ns   |
| t <sub>W</sub>        | pulse width       | LE HIGH; see Figure 8                             |     |     |     |      |
|                       |                   | V <sub>CC</sub> = 2.0 V                           | 65  | -   | -   | ns   |
|                       |                   | $V_{CC} = 4.5 V$                                  | 13  | -   | -   | ns   |
|                       |                   | V <sub>CC</sub> = 6.0 V                           | 11  | -   | -   | ns   |
| t <sub>su</sub>       | set-up time       | An to LE; see Figure 8                            |     |     |     |      |
|                       |                   | V <sub>CC</sub> = 2.0 V                           | 65  | -   | -   | ns   |
|                       |                   | $V_{CC} = 4.5 V$                                  | 13  | -   | -   | ns   |
|                       |                   | $V_{CC} = 6.0 V$                                  | 11  | -   | -   | ns   |
| t <sub>h</sub>        | hold time         | An to LE; see Figure 8                            |     |     |     |      |
|                       |                   | $V_{CC} = 2.0 V$                                  | 40  | -   | -   | ns   |
|                       |                   | $V_{CC} = 4.5 V$                                  | 8   | -   | -   | ns   |
|                       |                   | $V_{CC} = 6.0 V$                                  | 7   | -   | -   | ns   |

## Table 7. Dynamic characteristics ...continued

GND = 0 V;  $t_r = t_f = 6$  ns;  $C_L = 50$  pF.

| Symbol          | Parameter         | Conditions  | Min        | Тур | Max | Unit |
|-----------------|-------------------|---|------------|-----|-----|------|
| $T_{amb} = -40$ | 0 °C to +125 °C   |   |            |     |     |      |
| t <sub>pd</sub> | propagation delay | An to $\overline{Y}$ n; see Figure 6              | <u>[1]</u> |     |     |      |
|                 |                   | $V_{CC} = 2.0 V$                                  | -          | -   | 270 | ns   |
|                 |                   | $V_{CC} = 4.5 V$                                  | -          | -   | 54  | ns   |
|                 |                   | $V_{CC} = 6.0 V$                                  | -          | -   | 46  | ns   |
|                 |                   | LE to Yn; see Figure 7                            |            |     |     |      |
|                 |                   | V <sub>CC</sub> = 2.0 V                           | -          | -   | 285 | ns   |
|                 |                   | $V_{CC} = 4.5 V$                                  | -          | -   | 57  | ns   |
|                 |                   | $V_{CC} = 6.0 V$                                  | -          | -   | 48  | ns   |
|                 |                   | $\overline{E}1$ to $\overline{Y}n$ ; see Figure 7 |            |     |     |      |
|                 |                   | V <sub>CC</sub> = 2.0 V                           | -          | -   | 220 | ns   |
|                 |                   | $V_{CC} = 4.5 V$                                  | -          | -   | 44  | ns   |
|                 |                   | $V_{CC} = 6.0 V$                                  | -          | -   | 38  | ns   |
|                 |                   | E2 to $\overline{Y}$ n; see Figure 6              |            |     |     |      |
|                 |                   | V <sub>CC</sub> = 2.0 V                           | -          | -   | 220 | ns   |
|                 |                   | $V_{CC} = 4.5 V$                                  | -          | -   | 44  | ns   |
|                 |                   | $V_{CC} = 6.0 V$                                  | -          | -   | 38  | ns   |
| t <sub>t</sub>  | transition time   | see Figure 6                                      | [2]        |     |     |      |
|                 |                   | V <sub>CC</sub> = 2.0 V                           | -          | -   | 110 | ns   |
|                 |                   | $V_{CC} = 4.5 V$                                  | -          | -   | 22  | ns   |
|                 |                   | V <sub>CC</sub> = 6.0 V                           | -          | -   | 19  | ns   |
| t <sub>W</sub>  | pulse width       | LE HIGH; see Figure 8                             |            |     |     |      |
|                 |                   | V <sub>CC</sub> = 2.0 V                           | -          | -   | 75  | ns   |
|                 |                   | V <sub>CC</sub> = 4.5 V                           | -          | -   | 15  | ns   |
|                 |                   | V <sub>CC</sub> = 6.0 V                           | -          | -   | 13  | ns   |
| t <sub>su</sub> | set-up time       | An to LE; see Figure 8                            |            |     |     |      |
|                 |                   | V <sub>CC</sub> = 2.0 V                           | -          | -   | 75  | ns   |
|                 |                   | V <sub>CC</sub> = 4.5 V                           | -          | -   | 15  | ns   |
|                 |                   | $V_{CC} = 6.0 V$                                  | -          | -   | 13  | ns   |

## Table 7. Dynamic characteristics ...continued

 $GND = 0 V; t_r = t_f = 6 ns; C_L = 50 pF.$ 

#### Table 7. Dynamic characteristics ...continued

GND = 0 V;  $t_r = t_f = 6 ns$ ;  $C_L = 50 pF$ .

| Symbol         | Parameter | Conditions              | Min | Тур | Max | Unit |
|----------------|-----------|-------------------------|-----|-----|-----|------|
| t <sub>h</sub> | hold time | An to LE; see Figure 8  |     |     |     |      |
|                |           | $V_{CC} = 2.0 V$        | -   | -   | 45  | ns   |
|                |           | V <sub>CC</sub> = 4.5 V | -   | -   | 9   | ns   |
|                |           | $V_{CC} = 6.0 V$        | -   | -   | 8   | ns   |

[1]  $t_{pd}$  is the same as  $t_{PHL}$ ,  $t_{PLH}$ .

 $\label{eq:ttilde} [2] \quad t_t \text{ is the same as } t_{THL} \text{ and } t_{TLH}.$ 

[3]  $C_{PD}$  is used to determine the dynamic power dissipation (P<sub>D</sub> in  $\mu$ W).

 $P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \sum (C_L \times V_{CC}^2 \times f_o)$  where:

 $f_i$  = input frequency in MHz;

 $f_o = output frequency in MHz;$ 

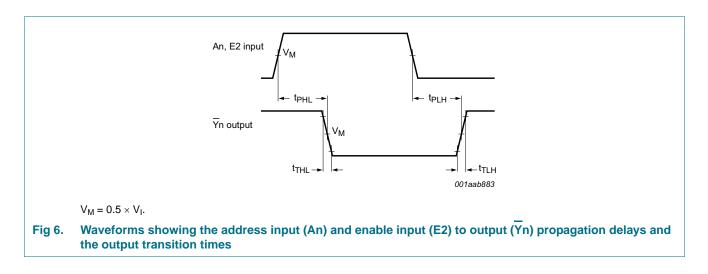
 $C_L$  = output load capacitance in pF;

V<sub>CC</sub> = supply voltage in V;

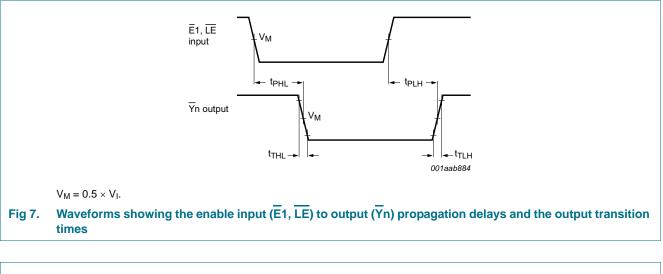
N = number of inputs switching;

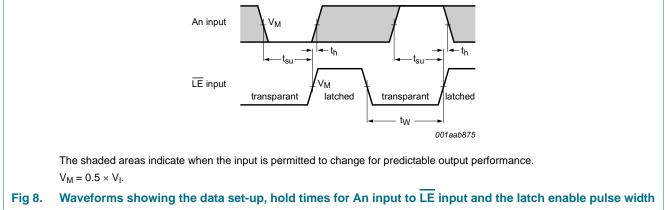
 $\Sigma(C_L \times V_{CC}^2 \times f_o)$  = sum of outputs.

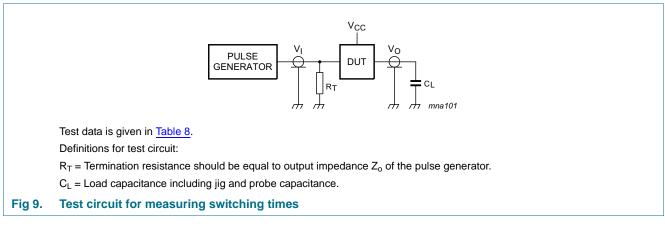
## 11. Waveforms



**Product data sheet** 



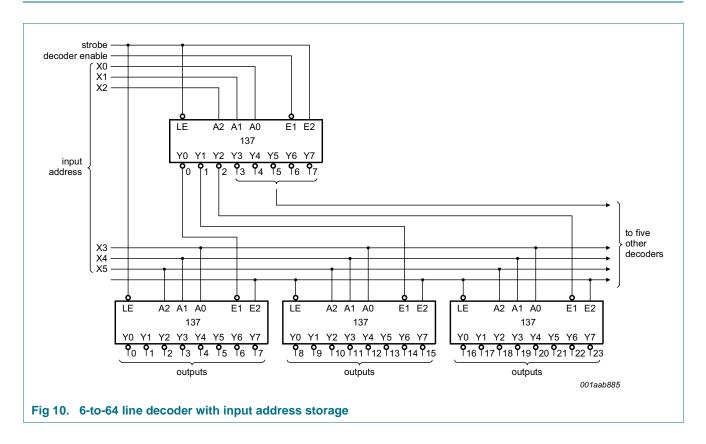




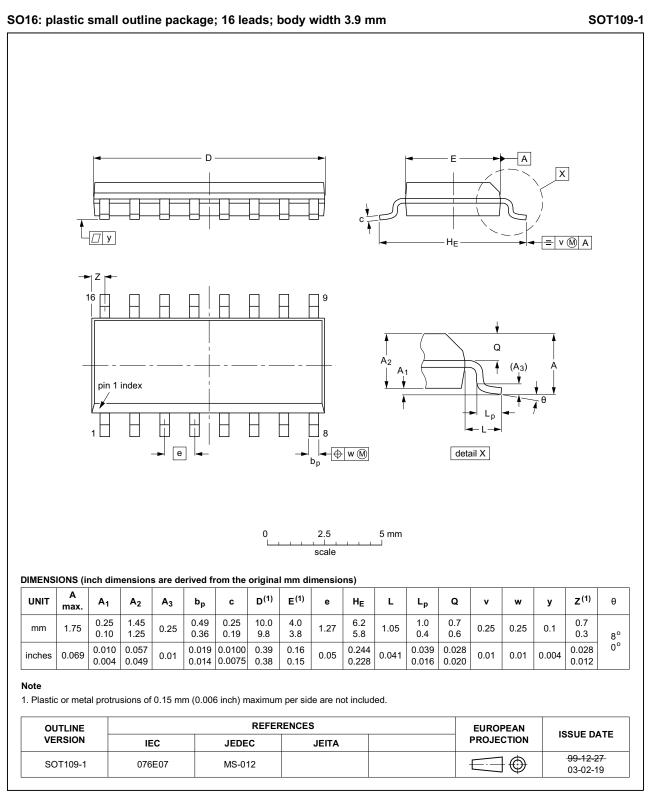
#### Table 8. Test data

| Supply          | Input           |                                 | Load  |
|-----------------|-----------------|---------------------------------|-------|
| V <sub>CC</sub> | VI              | t <sub>r</sub> , t <sub>f</sub> | CL    |
| 2.0 V           | V <sub>CC</sub> | 6 ns                            | 50 pF |
| 4.5 V           | V <sub>CC</sub> | 6 ns                            | 50 pF |
| 6.0 V           | V <sub>CC</sub> | 6 ns                            | 50 pF |
| 5.0 V           | V <sub>CC</sub> | 6 ns                            | 15 pF |

## **12.** Application information

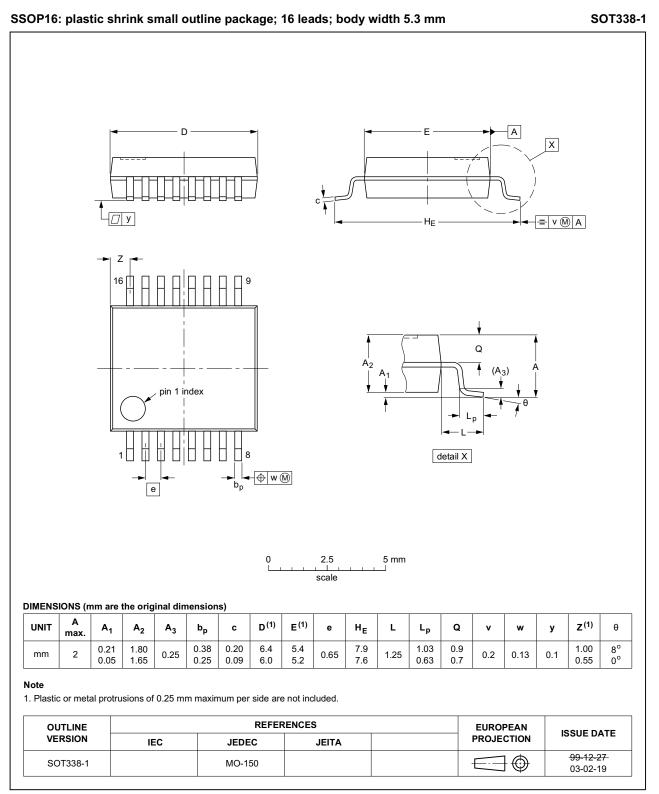


## 13. Package outline



#### Fig 11. Package outline SOT109-1 (SO16)

74HC137



#### Fig 12. Package outline SOT338-1 (SSOP16)

## 14. Abbreviations

| Table 9. Abbreviations |  |
|------------------------|--|
| Acronym                | Abbreviation                                   |
| CMOS                   | Complementary Metal Oxide Semiconductor        |
| DUT                    | Device Under Test                              |
| ESD                    | ElectroStatic Discharge                        |
| НВМ                    | Human Body Model                               |
| LSTTL                  | Low-power Schottky Transistor-Transistor Logic |
| ММ                     | Machine Model                                  |

## **15. Revision history**

#### Table 10. Revision history

| Document ID          | Release date  | Data sheet status     | Change notice | Supersedes          |  |  |
|----------------------|---|-----------------------|---------------|---------------------|--|--|
| 74HC137 v.4          | HC137 v.4 20151223  |                       | -             | 74HC137 v.3         |  |  |
| Modifications:       | Type numbers 74HC137N (SOT38-4) removed.  |                       |               |                     |  |  |
| 74HC137 v.3 20041111 |   | Product data sheet    | -             | 74HC_HCT137_CNV v.2 |  |  |
| Modifications:       | • The format of this data sheet has been redesigned to comply with the current presentation and information standard of Philips Semiconductors. |                       |               |                     |  |  |
|                      | <ul> <li>Removed type number 74HCT137.</li> </ul>   |                       |               |                     |  |  |
|                      | <ul> <li>Inserted family specification.</li> </ul>  |                       |               |                     |  |  |
| 74HC_HCT137_CNV v.2  | 19970827  | Product specification | -             | 74HC_HCT137 v.1     |  |  |
| 74HC_HCT137 v.1      | 19901201  | Product specification | -             | -                   |  |  |

## 16. Legal information

## 16.1 Data sheet status

| Document status[1][2]          | Product status <sup>[3]</sup> | Definition  |
|--------------------------------|-------------------------------|---|
| Objective [short] data sheet   | Development                   | This document contains data from the objective specification for product development. |
| Preliminary [short] data sheet | Qualification                 | This document contains data from the preliminary specification.                       |
| Product [short] data sheet     | Production                    | This document contains the product specification.                                     |

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

[3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL http://www.nexperia.com.

## 16.2 Definitions

**Draft** — The document is a draft version only. The content is still under internal review and subject to formal approval, which may result in modifications or additions. Nexperia does not give any representations or warranties as to the accuracy or completeness of information included herein and shall have no liability for the consequences of use of such information.

Short data sheet — A short data sheet is an extract from a full data sheet with the same product type number(s) and title. A short data sheet is intended for quick reference only and should not be relied upon to contain detailed and full information. For detailed and full information see the relevant full data sheet, which is available on request via the local Nexperia sales office. In case of any inconsistency or conflict with the short data sheet, the full data sheet shall prevail.

**Product specification** — The information and data provided in a Product data sheet shall define the specification of the product as agreed between Nexperia and its customer, unless Nexperia and

customer have explicitly agreed otherwise in writing. In no event however, shall an agreement be valid in which the Nexperia product is deemed to offer functions and qualities beyond those described in the Product data sheet.

## 16.3 Disclaimers

Limited warranty and liability — Information in this document is believed to be accurate and reliable. However, Nexperia does not give any representations or warranties, expressed or implied, as to the accuracy or completeness of such information and shall have no liability for the consequences of use of such information. Nexperia takes no responsibility for the content in this document if provided by an information source outside of Nexperia.

In no event shall Nexperia be liable for any indirect, incidental, punitive, special or consequential damages (including - without limitation - lost profits, lost savings, business interruption, costs related to the removal or replacement of any products or rework charges) whether or not such damages are based on tort (including negligence), warranty, breach of contract or any other legal theory.

Notwithstanding any damages that customer might incur for any reason whatsoever, Nexperia's aggregate and cumulative liability towards customer for the products described herein shall be limited in accordance with the *Terms and conditions of commercial sale* of Nexperia.

**Right to make changes** — Nexperia reserves the right to make changes to information published in this document, including without limitation specifications and product descriptions, at any time and without notice. This document supersedes and replaces all information supplied prior to the publication hereof. Suitability for use - Nexperia products are not designed,

authorized or warranted to be suitable for use in life support, life-critical or safety-critical systems or equipment, nor in applications where failure or malfunction of a Nexperia product can reasonably be expected to result in personal injury, death or severe property or environmental damage. Nexperia and its suppliers accept no liability for inclusion and/or use of Nexperia products in such equipment or applications and therefore such inclusion and/or use is at the customer's own risk.

**Applications** — Applications that are described herein for any of these products are for illustrative purposes only. Nexperia makes no representation or warranty that such applications will be suitable for the specified use without further testing or modification.

Customers are responsible for the design and operation of their applications and products using Nexperia products, and Nexperia accepts no liability for any assistance with applications or customer product design. It is customer's sole responsibility to determine whether the Nexperia product is suitable and fit for the customer's applications and products planned, as well as for the planned application and use of customer's third party customer(s). Customers should provide appropriate design and operating safeguards to minimize the risks associated with their applications and products.

Nexperia does not accept any liability related to any default, damage, costs or problem which is based on any weakness or default in the customer's applications or products, or the application or use by customer's third party customer(s). Customer is responsible for doing all necessary testing for the customer's applications and products using Nexperia products in order to avoid a default of the applications and the products or of the application or use by customer's third party customer(s). Nexperia does not accept any liability in this respect.

Limiting values — Stress above one or more limiting values (as defined in the Absolute Maximum Ratings System of IEC 60134) will cause permanent damage to the device. Limiting values are stress ratings only and (proper) operation of the device at these or any other conditions above those given in the Recommended operating conditions section (if present) or the Characteristics sections of this document is not warranted. Constant or repeated exposure to limiting values will permanently and irreversibly affect the quality and reliability of the device.

#### Terms and conditions of commercial sale - Nexperia

products are sold subject to the general terms and conditions of commercial sale, as published at <a href="http://www.nexperia.com/profile/terms">http://www.nexperia.com/profile/terms</a>, unless otherwise agreed in a valid written individual agreement. In case an individual agreement is concluded only the terms and conditions of the respective agreement shall apply. Nexperia hereby expressly objects to applying the customer's general terms and conditions with regard to the purchase of Nexperia products by customer.

**No offer to sell or license** — Nothing in this document may be interpreted or construed as an offer to sell products that is open for acceptance or the grant, conveyance or implication of any license under any copyrights, patents or other industrial or intellectual property rights.

74HC137

**Product data sheet** 

17 of 19

**Export control** — This document as well as the item(s) described herein may be subject to export control regulations. Export might require a prior authorization from competent authorities.

Non-automotive qualified products — Unless this data sheet expressly states that this specific Nexperia product is automotive qualified, the product is not suitable for automotive use. It is neither qualified nor tested in accordance with automotive testing or application requirements. Nexperia accepts no liability for inclusion and/or use of

non-automotive qualified products in automotive equipment or applications.

In the event that customer uses the product for design-in and use in automotive applications to automotive specifications and standards, customer (a) shall use the product without Nexperia's warranty of the product for such automotive applications, use and specifications, and (b) whenever customer uses the product for automotive applications beyond

## **17. Contact information**

Nexperia's specifications such use shall be solely at customer's own risk, and (c) customer fully indemnifies Nexperia for any liability, damages or failed product claims resulting from customer design and use of the product for automotive applications beyond Nexperia's standard warranty and Nexperia's product specifications.

**Translations** — A non-English (translated) version of a document is for reference only. The English version shall prevail in case of any discrepancy between the translated and English versions.

### 16.4 Trademarks

Notice: All referenced brands, product names, service names and trademarks are the property of their respective owners.

For more information, please visit: http://www.nexperia.com

For sales office addresses, please send an email to: salesaddresses@nexperia.com

## **18. Contents**

| 1    | General description 1              |
|------|------------------------------------|
| 2    | Features and benefits 1            |
| 3    | Ordering information 1             |
| 4    | Functional diagram 2               |
| 5    | Pinning information 3              |
| 5.1  | Pinning 3                          |
| 5.2  | Pin description 4                  |
| 6    | Functional description 4           |
| 6.1  | Function table 4                   |
| 7    | Limiting values 5                  |
| 8    | Recommended operating conditions 5 |
| 9    | Static characteristics 6           |
| 10   | Dynamic characteristics 8          |
| 11   | Waveforms 11                       |
| 12   | Application information 13         |
| 13   | Package outline 14                 |
| 14   | Abbreviations 16                   |
| 15   | Revision history 16                |
| 16   | Legal information 17               |
| 16.1 | Data sheet status 17               |
| 16.2 | Definitions 17                     |
| 16.3 | Disclaimers                        |
| 16.4 | Trademarks                         |
| 17   | Contact information 18             |
| 18   | Contents 19                        |



Компания «ЭлектроПласт» предлагает заключение долгосрочных отношений при поставках импортных электронных компонентов на взаимовыгодных условиях!

Наши преимущества:

- Оперативные поставки широкого спектра электронных компонентов отечественного и импортного производства напрямую от производителей и с крупнейших мировых складов;
- Поставка более 17-ти миллионов наименований электронных компонентов;
- Поставка сложных, дефицитных, либо снятых с производства позиций;
- Оперативные сроки поставки под заказ (от 5 рабочих дней);
- Экспресс доставка в любую точку России;
- Техническая поддержка проекта, помощь в подборе аналогов, поставка прототипов;
- Система менеджмента качества сертифицирована по Международному стандарту ISO 9001;
- Лицензия ФСБ на осуществление работ с использованием сведений, составляющих государственную тайну;
- Поставка специализированных компонентов (Xilinx, Altera, Analog Devices, Intersil, Interpoint, Microsemi, Aeroflex, Peregrine, Syfer, Eurofarad, Texas Instrument, Miteq, Cobham, E2V, MA-COM, Hittite, Mini-Circuits, General Dynamics и др.);

Помимо этого, одним из направлений компании «ЭлектроПласт» является направление «Источники питания». Мы предлагаем Вам помощь Конструкторского отдела:

- Подбор оптимального решения, техническое обоснование при выборе компонента;
- Подбор аналогов;
- Консультации по применению компонента;
- Поставка образцов и прототипов;
- Техническая поддержка проекта;
- Защита от снятия компонента с производства.



#### Как с нами связаться

**Телефон:** 8 (812) 309 58 32 (многоканальный) **Факс:** 8 (812) 320-02-42 **Электронная почта:** <u>org@eplast1.ru</u> **Адрес:** 198099, г. Санкт-Петербург, ул. Калинина, дом 2, корпус 4, литера А.